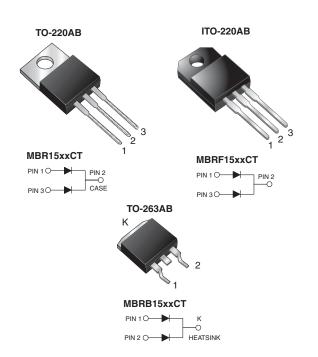
MBR(F,B)1535CT thru MBR(F,B)1560CT

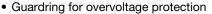
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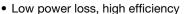
Dual Common Cathode Schottky Rectifier



PRIMARY CHARACTERISTICS					
I _{F(AV)}	7.5 A x 2				
V _{RRM}	35 V to 60 V				
I _{FSM}	150 A				
V _F	0.57 V, 0.65 V				
T _J max.	150 °C				

FEATURES

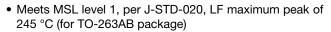




• Low forward voltage drop

· High forward surge capability

High frequency operation



- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix

meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	MBR1535CT	MBR1545CT	MBR1550CT	MBR1560CT	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	35	45	50	60		
Working peak reverse voltage	V_{RWM}	35	45	50	60	V	
Maximum DC blocking voltage	V_{DC}	35	45	50	60		
Maximum average forward rectified current total device		15					
at $T_C = 105 ^{\circ}C$ per diode	I _{F(AV)}	7.5					
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	150				А	
Peak repetitive reverse surge current per diode at $t_p = 2.0 \ \mu s$, 1 kHz	I _{RRM}	1	.0	0.5			
Voltage rate of change (rated V _R)	dV/dt	10 000			V/µs		
Operating junction temperature range	TJ	- 65 to + 150				°C	
Storage temperature range	T _{STG}	- 65 to + 175				C	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500				V	



MBR(F,B)1535CT thru MBR(F,B)1560CT

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)									
PARAMETER	SYMBOL	TEST CO	ONDITIONS MBR1535CT MBR1545CT		MBR1550CT	MBR1560CT	UNIT		
Maximum instantaneous forward voltage per diode	V _F (1)	I _F = 7.5 A	T _C = 25 °C	-		0.75		V	
		I _F = 7.5 A	T _C = 125 °C	0.57		0.65			
		I _F = 15 A	T _C = 25 °C	0.84		-			
		I _F = 15 A	T _C = 125 °C	0.72		-			
Maximum instantaneous reverse current at DC blocking voltage per diode	I _R ⁽²⁾	(2) Rated V _R	T _C = 25 °C	0.1		1.0		m A	
			T _C = 125 °C	1	5	5	0	mA	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT	
Maximum thermal resistance per diode	$R_{ hetaJA}$	60	-	60	°C/W	
iviaximum mermai resistance per diode	$R_{\theta JC}$	3.0	5.0	3.0	C/VV	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR1545CT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	MBRF1545CT-E3/45	1.99	45	50/tube	Tube		
TO-263AB	MBRB1545CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB1545CT-E3/81	1.35	81	800/reel	Tape and reel		
TO-220AB	MBR1545CTHE3/45 (1)	1.85	45	50/tube	Tube		
ITO-220AB	MBRF1545CTHE3/45 1)	1.99	45	50/tube	Tube		
TO-263AB	MBRB1545CTHE3/45 (1)	1.35	45	50/tube	Tube		
TO-263AB	MBRB1545CTHE3/81 (1)	1.35	81	800/reel	Tape and reel		

Note

(1) AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

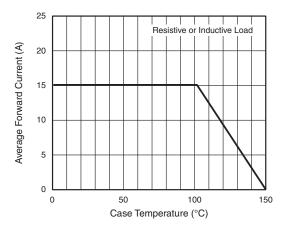


Fig. 1 - Forward Current Derating Curve

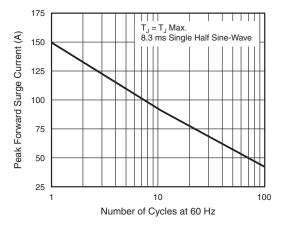


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

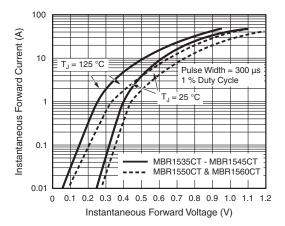


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

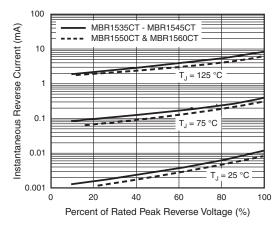


Fig. 4 - Typical Reverse Characteristics Per Diode

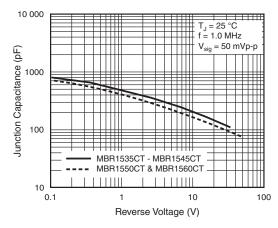


Fig. 5 - Typical Junction Capacitance Per Diode

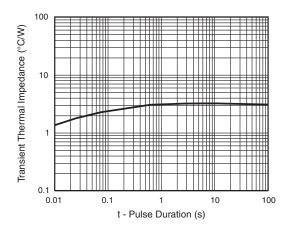


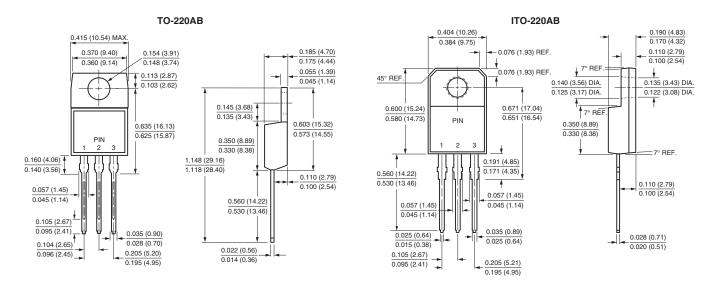
Fig. 6 - Typical Transient Thermal Impedance Per Diode



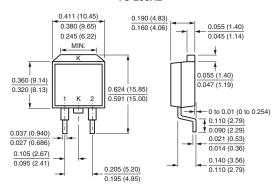
MBR(F,B)1535CT thru MBR(F,B)1560CT

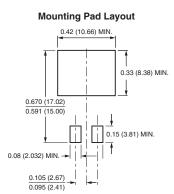
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-263AB







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